# 2SC3933

### Silicon NPN planer type

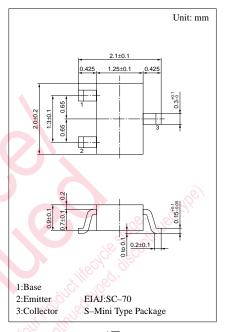
#### For UHF amplification/mixing

#### Features

- High power gain PG.
- High transition frequency f<sub>T</sub>.
- S-Mini type package, allowing downsizing of the equipment and automatic insertion through the tape packing and the magazine packing.

#### Absolute Maximum Ratings (Ta=25°C)

Parameter	Symbol	Ratings	Unit	
Collector to base voltage	$V_{CBO}$	30	V	
Collector to emitter voltage	$V_{CEO}$	20	V	
Emitter to base voltage	$V_{EBO}$	3	V	
Collector current	$I_{C}$	20	mA	
Collector power dissipation	$P_{C}$	150	mW	
Junction temperature	$T_{j}$	150	°C	
Storage temperature	$T_{stg}$	<b>−55 ~ +150</b>	°C	



Marking symbol: 1T

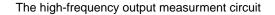
#### Electrical Characteristics (Ta=25°C)

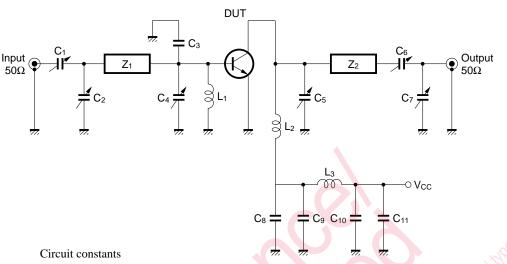
Parameter	Symbol	Conditions	min	typ	max	Unit
Collector cutoff current	$I_{CBO}$	$V_{CB} = 25V, I_{E} = 0$			1	μА
Emitter cutoff current	$I_{EBO}$	$V_{EB} = 3V, I_C = 0$			10	μА
Forward current transfer ratio	h <sub>FE1</sub>	$V_{CB} = 10V, I_E = -3mA$	40		200	
	h <sub>FE2</sub>	$V_{CB} = 10V, I_{E} = -10mA$	40		200	
	h <sub>FE3</sub>	$V_{CB} = 10V, I_E = -100\mu A$	60			
Transition frequency	f <sub>T</sub>	$V_{CB} = 10V$ , $I_E = -3mA$ , $f = 200MHz$	750	1100	1400	MHz
Collector output capacitance	C <sub>ob</sub>	$V_{CB} = 10V, I_{E} = 0, f = 1MHz$		0.7		pF
Common emitter reverse transfer capacitance	$C_{rb}$	$V_{CB} = 10V, I_E = 0, f = 1MHz$		0.15		pF
Power gain	PG*	$V_{CC} = 11V, V_{AGC} = 3V, f = 800MHz$	14			dB
Noise figure	NF*	$V_{CC} = 11V, V_{AGC} = 3V, f = 800MHz$			5	dB

\*PG, NF Refer to the measurment circuit

Panasonic

Transistor 2SC3933

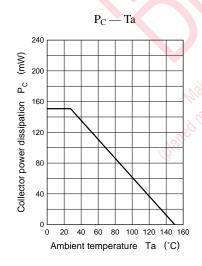




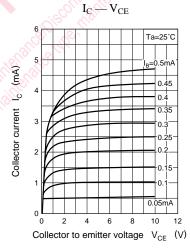
 $C_1, C_2, C_4 \sim C_7 : \sim 20 pF$ 

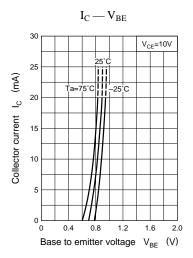
 $C_3$  : 5pF  $C_8$ ,  $C_{10}$  : 100pF  $C_9$ ,  $C_{11}$  : 1000pF

 $\begin{array}{lll} L_1, L_2 &: \phi 0.6 mm \ polyure thane, \ 2T, \ D=5 \\ L_3 &: \phi 0.6 mm \ polyure thane, \ 2T, \ D=5 \\ Z_1 &: copper \ board, \ 2.75 mm \times 20 mm \\ Z_2 &: copper \ board, \ 2.75 mm \times 20 mm \end{array}$ 

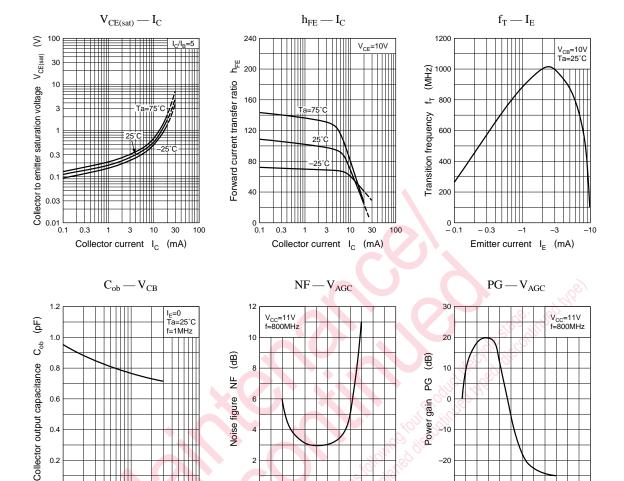


2





Transistor 2SC3933



2 3 4 V<sub>AGC</sub> (V)

Collector to base voltage V<sub>CB</sub> (V)

-30 └ 0

6

V<sub>AGC</sub> (V)

10

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